

# SEMICONDUCTOR TECHNICAL DATA

# **MBRF4030CT ~ MBRF40200CT**

# SCHOTTKY BARRIER RECTIFIER

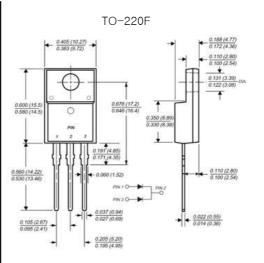
# VOLTAGE RANGE: 30 --- 200 V CURRENT:40.0A

### **FEATURES**

- Metal-semiconductor junction with guard ring
- Low forward voltage drop,low switching losses
- ♦ High surge capability
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ♦ The plastic material carries U/L recognition 94V-0

### **MECHANICAL DATA**

- $\Diamond$  Case:JEDEC ITO-220AB, molded plastic
- $\diamondsuit$  Terminals: Axial lead ,solderable per
  - MIL- STD-750, Method 2026
- ♦ Polarity: As marked
- ♦ Weight: 0.08ounces,2.24 grams





### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		Symbols	MBRF 4030CT	MBRF 4035CT	MBRF 4040CT	MBRF 4045CT	MBRF 4050CT	MBRF 4060CT	MBRF 40100CT	<b>MBRF</b> 40150CT	<b>MBRF</b> 40200CT	Units
Maximum repetitive peak reverse voltage		Vrrm	30	35	40	45	50	60	100	150	200	Volts
Maximum RMS voltage		VRMS	21	25	28	32	35	42	70	105	140	Volts
Maximum DC blocking voltage		VDC	30	35	40	45	50	60	100	150	200	Volts
Maximum average forward rectified current(see Fig. 1)	Per leg otal device	I(AV)	20.0 40.0							Amps		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		İfsm	300.0								Amps	
Maximum instantaneous forward voltage at 20,0A		VF	0.60			0.	75	0.85	0.	95	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T <sub>c</sub> = 25°C T <sub>c</sub> = 125°C	<b>I</b> R	0.2 30 50						mA			
Typical thermal resistance (Note 2)		$R_{\theta}$ JC	3.0									°C/W
Operating junction temperature range		TJ	-65 to+150									,C
Storage temperature range		Tstg	-65 to+150									,C

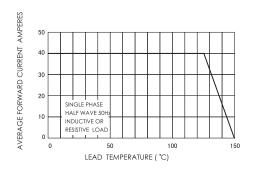
NOTE: 1. Pulse test:300us pulse width,1% duty cycle.

- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance junction to ambient

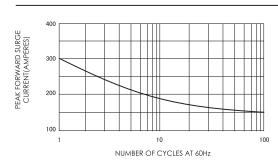


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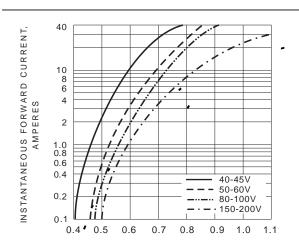
#### FIG.1-FORWARD CURRENT DERATING CURVE



### FIG.2-MAXIMUM NON-REPETITIVE PEAK **FORWARD SURGE CURRENT**

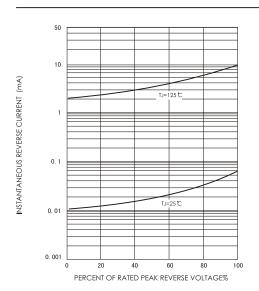


#### Fig.3- TYPICAL INSTANTANEOUS FORWARD **CHARACTERISTIC**

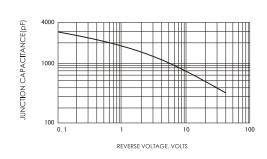


INSTANTANEOUS FORWARD VOLTAGE, VOLTS

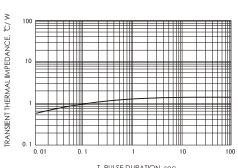
### FIG.4-TYPICAL REVERSE CHARACTERISTICS



### FIG.5-TYPICAL JUNCTION CAPACITANCE



## FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



T, PULSE DURATION ,sec.